

TRIAC (ISOLATED TYPE)

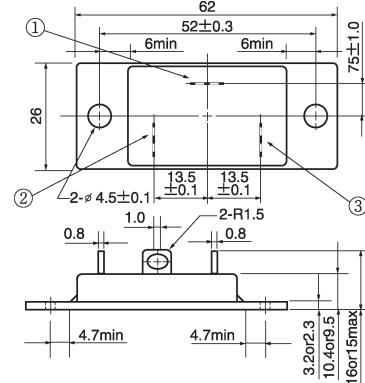
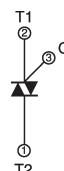
TG70AA40/60

TOP



TG70AA40/60 are isolated mould triac suitable for wide range of applications like copier, microwave oven, solid state switch, motor control, light control and heater control.

- $I_{T(AV)}$ 70A
- High surge capability 600A
- Isolated Nounting (AC650V)
- Tab Terminals



Unit : mm

Maximum Ratings

Symbol	Item	Ratings		Unit
		TG70AA40	TG70AA60	
V_{DRM}	Repetitive Peak Off-State Voltage	400	600	V
V_{DSM}	Non-Repetitive Peak Off-State Voltage	450	650	V

Symbol	Item	Conditions	Ratings	Unit
$I_{T(RMS)}$	R.M.S. On-State Current	$T_c=58^\circ C$	70	A
I_{TSM}	Surge On-State Current	One cycle, 50Hz/60Hz, peak, non-repetitive	1080/1200	A
I^2t	I^2t		6000	A^2S
P_{GM}	Peak Gate Power Dissipation		10	W
$P_{G(AV)}$	Average Gate Power Dissipation		1	W
I_{GM}	Peak Gate Current		3	A
V_{GM}	Peak Gate Voltage		10	V
di/dt	Critical Rate of Rise of On-State Current	$I_G=100mA, T_j=25^\circ C, V_D=\frac{1}{2}V_{DRM}, dI/dt=1A/\mu s$	50	$A/\mu s$
T_j	Operating Junction Temperature		-40~+125	$^\circ C$
T_{stg}	Storage Temperature		-40~+125	$^\circ C$
V_{iso}	Isolation Breakdown Voltage (R.M.S.)	A.C.1 minute	2500	V
	Mounting Torque (Mounting M4)	Recommended Value 1.0~1.4 (10~14)	1.5 (15)	$N \cdot m$ (kgf·cm)
	Mass			g

Electrical Characteristics

Symbol	Item	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
I_{DRM}	Repetitive Peak Off-State Current	$V_D=V_{DRM}$, Single phase, half wave, $T_j=125^\circ C$			10	mA
V_{TM}	Peak On-State Voltage	On-State Current, 100A, $I_T=25A$, Inst. measurement			1.35	V
I_{GT1}^+	1	Gate Trigger Current	$T_j=25^\circ C, I_T=1A, V_D=6V$		50	mA
I_{GT1}^-	2		$T_j=25^\circ C, I_T=1A, V_D=6V$		50	
I_{GT3}^+	3					
I_{GT3}^-	4		$T_j=25^\circ C, I_T=1A, V_D=6V$		50	
V_{GT1}^+	1	Gate Trigger Voltage	$T_j=25^\circ C, I_T=1A, V_D=6V$		3	V
V_{GT1}^-	2		$T_j=25^\circ C, I_T=1A, V_D=6V$		3	
V_{GT3}^+	3					
V_{GT3}^-	4		$T_j=25^\circ C, I_T=1A, V_D=6V$		3	
V_{GD}	Non-Trigger Gate Voltage	$T_j=125^\circ C, V_D=\frac{1}{2}V_{DRM}$	0.2			V
dv/dt	Critical Rate of Rise on-State Voltage,min.	$T_j=125^\circ C, V_D=\frac{2}{3}V_{DRM}$, Exponential wave.	50			$V/\mu s$
$[dv/dt]_c$	Critical Rate of Rise off-State Voltage at commutation	$T_j=125^\circ C, V_D=\frac{2}{3}V_{DRM}$, $[dv/dt]_c=8A/ms$	6			$V/\mu s$
I_H	Holding Current	$T_j=25^\circ C$		50 100	mA	
$R_{th(j-c)}$	Thermal Impedance	Junction to case			0.83	$^\circ C/W$

